NSN 5962-01-290-2302

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View Online at https://aerobasegroup.com/nsn/5962-01-290-2302 **Overall Height:** 0.400 inches **Body Length:** 1.060 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.130 inches and 0.185 inches **Maximum Power Dissipation Rating:** 1.1 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and bipolar and programmed **Inclosure Material:** Ceramic Inclosure Configuration: Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** D-8 mil-m-38510 **Current Rating Per Characteristic:** 90.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** Registered and-or gate array Voltage Rating And Type Per Characteristic: -0.5 volts power source and 12.0 volts power source **Time Rating Per Chacteristic:** 25.00 nanoseconds delay Memory Device Type: Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

